

Ultralow-Voltage ETR Controller with On-Chip LCD Driver

Preliminary

Overview

The LC72314W, LC72315W and LC72316W are ultralow-voltage (0.9 to 1.8 V) electronic tuning microcontrollers that include a PLL that operates up to 250 MHz and a 1/4 duty 1/2 bias LCD driver on chip. This IC includes an on-chip DC-DC converter that can easily create the power supply voltages needed for electronic tuning and contribute to reducing end product costs. This IC is optimal for portable audio equipment that must operate from a single battery.

Function

• Program memory (ROM):

4096 × 16 bits (8K bytes) : LC72314W
 6144 × 16 bits (12K bytes): LC72315W
 8192 × 16 bits (16K bytes): LC72316W

• Data memory (RAM):

 -256×4 bits: LC72314W

 $--512 \times 4$ bits: LC72315W/72316W

• Cycle time: 40 µs (all 1-word instructions)

• Stack: 8 levels

• LCD driver:

48 to 112 segments (1/4 duty, 1/2 bias drive)

• Interrupts: Two external interrupts

Timer interrupts (1, 5, 10, and 50 ms)

- A/D converter: Four input channels (6-bit successive approximation conversion)
- Input ports: 11 ports (of which three can be switched for use as A/D converter inputs)
- Output ports: 8 ports (of which 1 can be switched for use as the beep tone output and 4 are open-drain ports)
- I/O ports: 29 ports (of which 16 can be switched for use as LCD ports and as mask options, of which 3 can be switched for use as serial I/O ports)

- Serial I/O: One system (LC72315W/72316W)
- PLL: Reference frequencies:

1, 3, 3.125, 5, 6.25, 12.5, and 25 kHz

• Input frequencies:

FM band: 10 to 250 MHz AM band (high): 2 to 20 MHz AM band (low): 0.5 to 10 MHz

• Input sensitivity: FM band:

35~mVrms (130 MHz to 250 MHz: 50~mVrms)

AM band (high, low): 35 mVrms

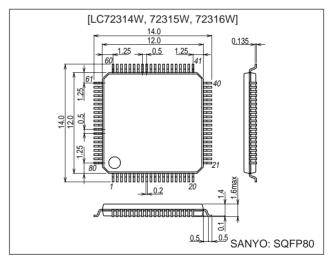
- IF counter: HCTR input pin 0.4 to 15 MHz (35 mVrms)
- External reset input: During CPU and PLL operations, instruction execution is started from location 0.

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Package Dimensions

unit: mm

3220-SQFP80



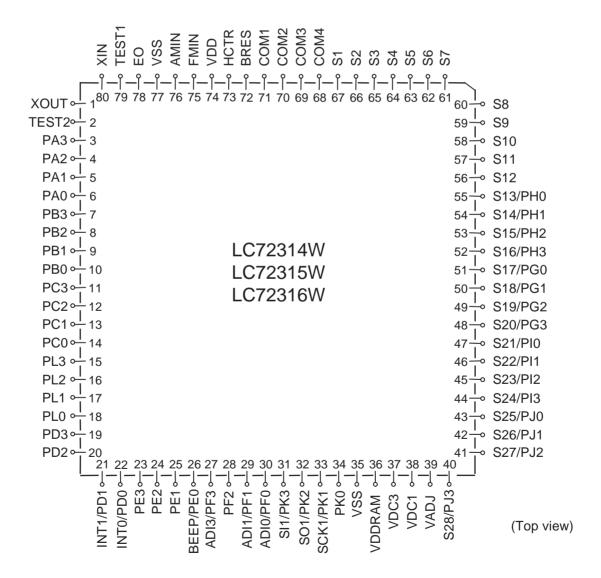
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- Built-in power-on reset circuit:
 The CPU starts execution from location 0 when power is first applied.
- Halt mode: The controller-operating clock is stopped.
- Backup mode: The crystal oscillator is stopped.
- Static power-on function:
 Backup state is cleared with the PF port
- Beep tone: 1.5 and 3.1 kHz
 Built-in DC-DC converter:
 For LCD and A/D converter use (3 V)
 Can also be used for TU + B creation by using a secondary coil.

- Built-in remaining battery life verification function: Converts the V_{DD} pin level to digital.
- Memory retention voltage: 0.8 V or higher
- Dedicated memory power supply: The RAM retention time has been increased by the provision of a dedicated memory power supply.
- Package: SQFP-80 (0.5-mm pitch)
- V_{DD} power supply: 0.9 to 1.8 V
- Operating frequency: 75 kHz

Pin Assignment



Specifications Absolute Maximum Ratings at $Ta=25^{\circ}C,\,V_{SS}=0~V$

Parameter	Symbol	Conditions	Ratings	Unit
	V _{DD} 1 max	V _{DD}	-0.3 to +3.0	V
Maximum supply voltage	V _{DD} 3 max	V _{DD} RAM	-0.3 to +4.0	V
	V _{DD} 4 max	VDC3	-0.3 to +4.0	V
Input voltage	V _{IN} 1	FMIN, AMIN, HCTR	-0.3 to V _{DD} 1 +0.3	V
Input voltage	V _{IN} 2	PA, PC, PD, PF, PG, PH, PI, PJ, PL, BRES	-0.3 to V _{DD} 1 +0.3	V
	V _{OUT} 1	PE	-0.3 to +7	V
Output voltage	V _{OUT} 2	PB, PC, PD, PG, PH, PI, PJ, PK, PL	-0.3 to V _{DD} 1 +0.3	V
Output voltage	V _{OUT} 3	VDC1, EO	-0.3 to V _{DD} 4 +0.3	V
	V _{OUT} 4	COM1 to COM4, S1 to S28	-0.3 to V _{DD} 4 +0.3	V
	I _{OUT} 1	PC, PD, PG, PH, PI, PJ, PK, PL, EO	0 to 3	mA
	I _{OUT} 2	РВ	0 to 1	mA
Output current	I _{OUT} 3	PE	0 to 2	mA
	I _{OUT} 4	S1 to S28	300	μA
	I _{OUT} 5	COM1 to COM4	3	mA
Allowable power dissipation	Pdmax	$Ta = -10 \text{ to } +60^{\circ}\text{C}$	100	mW
Operating temperature	Topr		-10 to +60	°C
Storage temperature	Tstg		-45 to +125	°C

Allowable Operating Ranges at $Ta=-10~to~+60^{\circ}C,~V_{DD}=0.9~to~1.8~V$

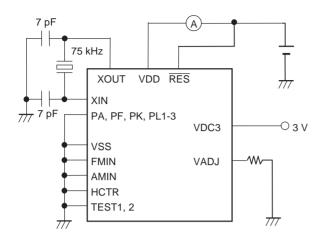
Parameter	Cumbal	Conditions		Ratings		Unit	
Parameter	Symbol	Conditions	min	typ	max	Onit	
	V _{DD} 1	Voltage applied to the V _{DD} pin	0.9	1.3	1.8		
Supply voltage	V _{DD} 3	Voltage applied to the V _{DD} RAM pin	2.7	3.0	3.3		
Supply voltage	V _{DD} 4	Voltage applied to the VDC3 pin	2.7	3.0	3.3]	
	V _{DD} 5	Memory retention voltage	0.8				
	V _{IH} 1	Ports PC, PD, PG, PH, PI, PJ, PK, and PL	0.7 V _{DD} 1		V _{DD} 1	V	
Input high-level voltage	V _{IH} 2	Port PA	0.8 V _{DD} 1		V _{DD} 1	V	
Input high-level voltage	V _{IH} 3	Port PF	0.8 V _{DD} 1		V _{DD} 1	V	
	V _{IH} 4	Port BRES	0.6 V _{DD} 1		V _{DD} 1	V	
	V _{IL} 1	Ports PC, PD, PG, PH, PI, PJ, PK, and PL	0		0.3 V _{DD} 1	V	
Input low-level voltage	V _{IL} 2	Port PA	0		0.2 V _{DD} 1	V	
Input low-level voltage	V _{IL} 3	Port PF	0		0.2 V _{DD} 1	V	
	V _{IL} 4	Port BRES	0		0.2 V _{DD} 1	V	
	V _{IN} 1	XIN	0.5		0.6	Vrms	
Input amplitude	V _{IN} 2	FMIN, AMIN, HCTR: V _{DD} 1 = 0.9 to 1.8 V	0.035		0.35	Vrms	
	V _{IN} 3	FMIN: V _{DD} 1 = 0.9 to 1.8 V	0.05		0.35	Vrms	
Input voltage range	V _{IN} 4	ADI0, ADI1, ADI3, V _{DD} 1	0		V _{DD} 4	V	
	F _{IN} 1	XIN: CI ≤ 35 kΩ	70	75	80	kHz	
	F _{IN} 2	FMIN: $V_{IN}2$, $V_{DD}1 = 0.9$ to 1.8 V	10		130	MHz	
Input frequency	F _{IN} 3	FMIN: V _{IN} 3, V _{DD} 1 = 0.9 to 1.8 V	130		250	MHz	
input nequency	F _{IN} 4	AMIN(L): V _{IN} 2, V _{DD} 1 = 0.9 to 1.8 V	0.5		10	MHz	
	F _{IN} 5	AMIN(H): V _{IN} 2, V _{DD} 1 = 0.9 to 1.8 V	2.0		20	MHz	
	F _{IN} 5	HCTR: V _{IN} 2, V _{DD} 1 = 0.9 to 1.8 V	0.4		15	MHz	

Electrical Characteristics under allowable operating conditions

Parameter	Symbol	Symbol Conditions			Ratings						
- aramotor	Cymson	Conditions	min	typ	max	Unit					
	I _{IH} 1	XIN: V _{DD} 1 = 1.3 V			3	μA					
	I _{IH} 2	FMIN, AMIN, HCTR: V _{DD} 1 = 1.3 V	3	8	20	μA					
Input high-level current	I _{IH} 3	Port PF: V _{DD} 1 = 1.3 V			4	μA					
	I _{IH} 4	PA (without pull-down resistors), the PC, PD, PG, PH, PI, PJ, PK, and PL ports, and BRES: $V_{DD}1 = 1.3 \text{ V}$			3	μА					
	I _{IL} 1	XIN: $V_{DD}1 = V_{SS}$			-3	μA					
	I _{IL} 2	FMIN, AMIN, HCTR: $V_{DD}1 = V_{SS}$	-3	-8	-20	μA					
Input low-level current	I _{IL} 3	Port PF: V _{DD} 1 = V _{SS}			-4	μA					
input few fever current	I _{IL} 4	PA (without pull-down resistors), the PC, PD, PG, PH, PI, PJ, PK, and PL ports, and BRES: V _{DD} 1 = V _{SS}			-3	μА					
Input floating voltage	V _{IF}	PA (with pull-down resistors)			0.05 V _{DD} 1	٧					
	R _{PD} 1	PA/PF (with pull-down resistors), V _{DD} 1 = 1.3 V	75	100	200	kΩ					
Pull-down resistor	R _{PD} 2	TEST1, TEST2 (with pull-down resistors), V _{DD} 1 = 1.3 V		10		kΩ					
Hysteresis	V _H	BRES	0.1 V _{DD} 1	0.2 V _{DD} 1		٧					
	V _{OH} 1	PB: I _O = 1 mA	V _{DD} 1 – 0.3 V _{DD} 1			V					
	V _{OH} 2	PC, PD, PG, PH, PI, PJ, PK, and PL: I _O = 1 mA	V _{DD} 1 – 0.3 V _{DD} 1			V					
Output high-level voltage	V _{OH} 3	EO: I _O = 500 μA	V _{DD} 4 – 0.3 V _{DD} 4			V					
	V _{OH} 4	XOUT: I _O = 1 μA	V _{DD} 1 – 0.3 V _{DD} 1			V					
	V _{OH} 5	S1 to S28: I _O = 20 μA	V _{DD} 4 –1			٧					
	V _{OH} 6	COM1, COM2, COM3, COM4: I _O = 100 μA	V _{DD} 4 –1			V					
	V _{OH} 7	VDC1: I _O = 1 mA	V _{DD} 4 –1			V					
	V _{OL} 1	PB: I _O = -50 μA			0.3 V _{DD} 1	V					
	V _{OL} 2	PC, PD, PE, PG, PH, PI, PJ, PK, and PL: I _O = -1 mA			0.3 V _{DD} 1	V					
	V _{OL} 3	EO: I _O = -500 μA			0.3 V _{DD} 4	V					
0	V _{OL} 4	XOUT: I _O = -1 μA			0.3 V _{DD} 1	V					
Output low-level voltage	V _{OL} 5	S1 to S28: I _O = -20 μA			V _{DD} 4 –2	V					
	V _{OL} 6	COM1, COM2, COM3, COM4: I _O = -100 μA			V _{DD} 4 –2	V					
	V _{OL} 7	PE: I _O = 2 mA			0.6 V _{DD} 1	V					
Output off leakage current	I _{OFF} 1	Ports PB, PC, PD, PG, PH, PI, PJ, PK, PL, and EO	-3		+3	μA					
	I _{OFF} 2	Port PE	-100		+100	nA					
A/D converter error		ADI0, ADI1, ADI3 V _{DD} 1	-1/2		+1/2	LSB					
	I _{DD} 1	V _{DD} 1 = 1.3 V: F _{IN} 2 130 MHz, Ta = 25°C		10	30	mA					
	I _{DD} 2	V _{DD} 1 = 1.3 V: In PLL stop mode, Ta = 25°C		0.15		mA					
Current drain	I _{DD} 3	V _{DD} 1 = 1.3 V: In HALT mode, Ta = 25°C *1		0.1		mA					
	I _{DD} 4	$V_{DD}1 = 1.8 \text{ V}$, with the oscillator stopped, Ta = 25°C *2		1		μА					

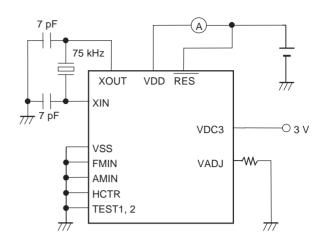
Note*: The halt mode current drain is due to 20 instruction being executed every 125 ms.

*1. Halt and PLL STOP mode current test circuit



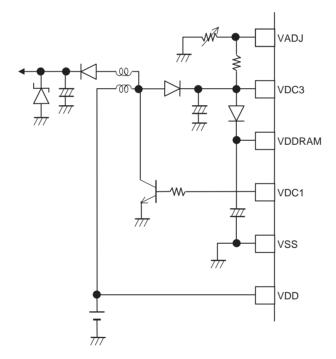
With all ports other than those specified above left open. With output mode selected for PC and PD. With segments S13 to S28 selected.

*2. Backup mode current test circuit

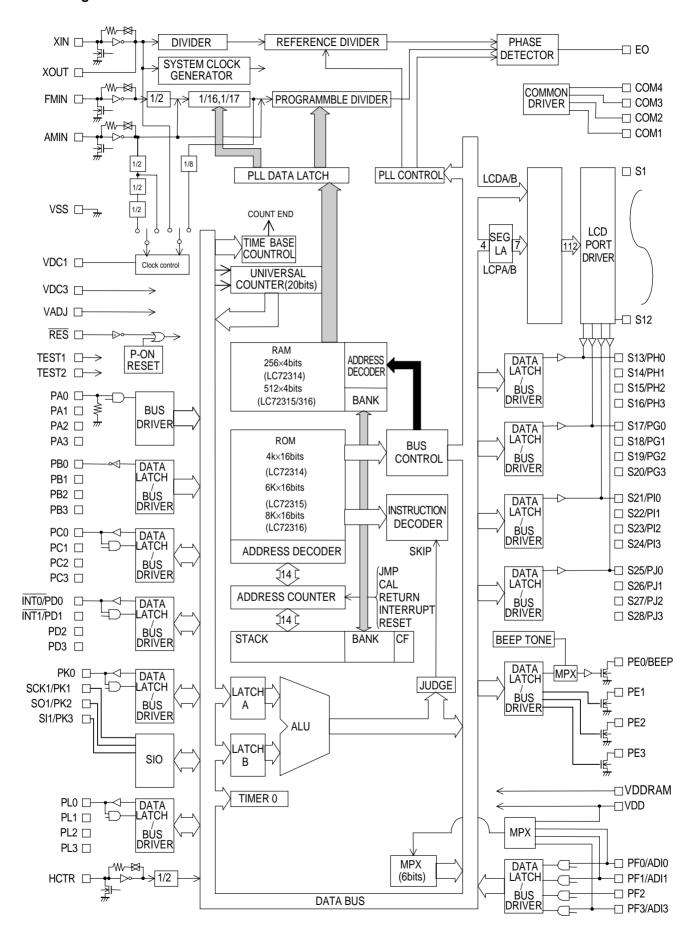


With all ports other than those specified above left open. With output mode selected for PC and PD. With segments S13 to S28 selected.

DC-DC Converter Application



Block Diagram



Pin Functions

Pin No.	Pin	I/O	Function	I/O circuit
80 1	XIN XOUT	I 0	75 kHz oscillator connections	
79 2	TEST1 TEST2	I I	IC testing. These pins must be connected to ground during normal operation.	_
6 5 4 3	PA0 PA1 PA2 PA3	ı	Special-purpose ports for key return signal input designed with a low threshold voltage. When a key matrix is formed in combination with port PB, simultaneous multiple key presses with up to 3 keys can be detected. The pull-down resistors are set up for all four pins at the same time with the IOS instruction (PWn = 2.b1). This setting cannot be specified for individual pins. In backup mode, these pins go to the input disabled state, and the pull-down resistors are disabled after a reset.	Input with built-in pull-down resistor
10 9 8 7	PB0 PB1 PB2 PB3	0	Unbalanced CMOS outputs. These outputs are switched with the IOS 0 instruction. Since these outputs are unbalanced, no diodes are required to prevent short circuits due to simultaneous multiple key presses. These outputs go to the high-impedance output state in backup mode. After a reset, they go to the high-impedance output state and remain in that state until an output instruction (OUT, SPB, or RPB) is executed.	Unbalanced CMOS push-pull
14 13 12 11 22 21 20 19	PC0 PC1 PC2 PC3 INT0/PD0 INT1/PD1 PD2 PD3 *2	I/O	General-purpose I/O ports. PD0, PD1 can be used as an external interrupt port. The IOS instruction (Pwn = 4, 5) is used for switching the general-purpose I/O port function, and these ports can be set to input or output in 1-bit units. (0: input, 1: output) In backup mode they go to the input disabled high-impedance state. After a reset, they switch to the general-purpose input port function.	CMOS push-pull
26 25 24 23	BEEP/PE0 PE1 PE2 PE3	0	General-purpose output and beep tone output shared function ports (PE0 only). The BEEP instruction is used to switch PE0 between the general-purpose output port and beep tone output functions. To use PE0 as a general-purpose output port, execute a BEEP instruction with b2 set to 0. Set b2 to 1 to use PE0 as the beep tone output port. The b0 and b1 bits are used to select the beep tone frequency. There are two beep tone frequencies supported. *: When PE0 is set up as the beep tone output, executing an output instruction to PE0 only changes the state of the internal output latch, it does not affect the beep tone output in any way. Only the PE0 pin can be switched between the general-purpose output function and the beep tone output function; the PE1 to PE3 pin only functions as a general-purpose output. These pins go to the high-impedance state in backup mode and remain in that state until an output instruction or a BEEP instruction is executed. Since these ports are open-drain ports, resistors must be inserted between these pins and V _{DD} . These ports are set to general-purpose output port function after a reset.	N-channel open-drain
18 17 16 15 34 33 32 31	PL0 PL1 PL2 PL3 PK0 SCK1/PK1 SO1/PK2 SI1/PK3	I/O I I I I/O I/O I/O I/O I/O	Shared function pins used as either general-purpose I/O ports or a serial I/O port (only port PK). When used as general-purpose I/O ports, the I/O direction can be switched in single bit units with the IOS instruction (Pwn = 1, C). The IOS instruction (with Pwn = 1, b2) is used to switch the function between the general-purpose I/O port and the serial I/O port function. (0: general-purpose I/O port, 1: serial I/O) In backup mode (Iow power mode) these pins go to the input disabled high-impedance state. After a reset, the general-purpose input port function is selected. Pins PL1, PL2, and PL3 are used as input ports.	CMOS input CMOS push-pull

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Pin No.	Pin	I/O	Function	I/O circuit
30 29 28 27	PF0/ADI0 PF1/ADI1 PF2 PF3/ADI3	I	General-purpose input and A/D converter input shared function ports. The IOS instruction (Pwn = FH) is used to switch between the general-purpose input and A/D converter port functions. The general-purpose input and A/D converter port functions can be switched in a units, with 0 specifying general-purpose input, and 1 specifying the A/D converter input function. To select the A/D converter function, set up the A/D converter pin with an IOS instruction with Pwn set to 1. The A/D converter is started with the UCC instruction (b3 = 1, b2 = 1). The ADCE flag is set when the conversion completes. The INR instruction is used to read in the data. **: If an input instruction is executed for one of these pins which is set up for analog input, the read in data will be at the low level since CMOS input is disabled. In backup mode these pins go to the input disabled high-impedance state. These ports are set to their general-purpose input port function after a reset. The A/D converter is a 6-bit successive approximation type converter, and features a conversion time of 1.28 ms. Note that the full-scale A/D converter voltage (3FH) is (63/96) V _{DD} .	CMOS input/analog input
40 41 42 43 44 45 46 47 48 49 50 51 52 53 54 55	PJ3/S28 PJ2/S27 PJ1/S26 PJ0/S25 PI3/S24 PI2/S23 PI1/S22 PI0/S21 PG3/S20 PG2/S19 PG1/S18 PG0/S17 PH3/S16 PH2/S15 PH1/S14 PH0/S13 *2	I/O	LCD driver segment output and general-purpose I/O shared function ports. The IOS instruction is used for switching between the segment output and general-purpose I/O functions and between input and output for the general-purpose I/O port function. • When used as segment output ports The general-purpose I/O port function is selected with the IOS instruction (Pwn = 8). b0 to b3 = S17 to 20/PG0 to 3 (0: segment output 1: general-purpose I/O) The general-purpose I/O port function is selected with the IOS instruction (Pwn = 9). b0 to b3 = S13 to 16/PH0 to 3 (0: segment output 1: general-purpose I/O) The general-purpose I/O port function is selected with the IOS instruction (Rwn = D) b0 to b3 = S21 to 24/PI0 to 3 (0: segment output 1: general-purpose I/O) The general-purpose I/O port function is selected with the IOS instruction (Rwn = E) b0 to b3 = S25 to 28/PJ0 to 3 (0: segment output 1: general-purpose I/O) • When used as general-purpose I/O ports The IOS instruction (Pwn = 6, 7, A, B) is used to select input or output. Note that the mode can be set in a bit units.	CMOS push-pull
56 to 67	S12 to S1	0	instruction must be used as described above to set up the port function. LCD driver segment output pins. A 1/4-duty 1/2-bias drive technique is used. The frame frequency is 75 Hz. In backup mode, these outputs are fixed at the low level. After a reset, these outputs are fixed at the low level.	CMOS push-pull
68 69 70 71	COM4 COM3 COM2 COM1	0	LCD driver common output pins. A 1/4-duty 1/2-bias drive technique is used. The frame frequency is 75 Hz. In backup mode, these outputs are fixed at the low level. After a reset, these outputs are fixed at the low level.	

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Pin No.	Pin	I/O	Function	I/O circuit				
140.	1 111	","	1 difetori					
72	RES	I	System reset input. In CPU operating mode or halt mode, applications must apply a low level for at least one full machine cycle to reset the system and restart execution with the PC set to location 0. This pin is connected in parallel with the internal power on reset circuit.					
38	VDC1	0	Output for the 3 V step-up circuit clock. Outputs 1/2 the AM local oscillator frequency in AM reception mode, and 1/256 the FM local oscillator or 75 kHz in FM reception mode.					
37	VDC3	I	Voltage stepped up by the DC-DC converter (3 V) May also be used to input an equivalent voltage.					
36	VDDRAM	I	RAM backup power supply. Connected to the VDC3 voltage through a diode.					
39	VADJ	0	VDC3 voltage adjustment pin. Insert a 10 k Ω variable resistor between this pin and ground to adjust the VDC3 voltage.					
75	FMIN	I	FM VCO (local oscillator) input. This pin is selected with the PLL instruction CW1. The input must be capacitor coupled. Input is disabled in backup mode, in halt mode, after a reset, and in PLL stop mode.	CMOS amplifier input				
76	AMIN	ı	AM VCO (local oscillator) input. This pin and the bandwidth are selected with the PLL instruction CW1. CW1 b1, b0	CMOS amplifier input				
73	HCTR	ı	Dedicated input port for the universal counter. • For frequency measurement, select the HCTR frequency measurement mode and measurement time with a UCS instruction (b3 = 0, b2 = 0) and start the counter with a UCC instruction. UCS b3, b2 Input pin measurement mode 0 0 HCTR frequency measurement 0 1	CMOS amplifier input				
78	EO	0	Main charge pump output. When the local oscillator frequency divided by N is higher than the reference frequency a high level is output, when lower, a low level is output, and the pin is set to the high-impedance state when the frequencies match. This output goes to the high-impedance state in backup mode, in halt mode, after a reset, and in PLL stop mode.	CMOS push-pull				
77 35 74	V _{SS} V _{SS} V _{DD}	_	Power supply pin. This pin must be connected to ground. This pin must be connected to ground. This pin must be connected to V _{DD} . Supports A/D converter.	_				

Note*: When a pin in an I/O switching port is used as an output, applications must first set up the data with an OUT, SPB, or RPB instruction and then set up output mode with an IOS instruction.

LC72314 Series Instruction Set

Terminology

ADDR : Program memory address

b : Borrow C : Carry

DH : Data memory address High (Row address) [2 bits]
DL : Data memory address Low (Column address) [4 bits]

I : Immediate data [4 bits]
M : Data memory address
N : Bit position [4 bits]
Rn : Resister number [4 bits]
Pn : Port number [4 bits]

PW : Port control word number [4 bits]

r : General register (One of the addresses from 00H to 0FH of BANK0)

(), [] : Contents of register or memory M (DH, DL) : Data memory specified by DH, DL

Instruction group	Maamania	Ope	rand	Function	Operations function	Instruction format													
Instru	Mnemonic	1st	2nd	Function	Operations function									3 2 1 0					
	AD	r	М	Add M to r	$R \leftarrow (r) + (M)$	0	1	0	0	0	0	DH	DL	r					
	ADS	r	М	Add M to r, then skip if carry	$R \leftarrow (r) + (M)$, skip if carry	0	1	0	0	0	1	DH	DL	r					
sus	AC	r	М	Add M to r with carry	$R \leftarrow (r) + (M) + C$	0	1	0	0	1	0	DH	DL	r					
Addition instructions	ACS	r	М	Add M to r with carry, then skip if carry	$R \leftarrow (r) + (M) + C$ skip if carry	0	1	0	0	1	1	DH	DL	r					
l in	Al	М	- 1	Add I to M	$M \leftarrow (M) + I$	0	1	0	1	0	0	DH	DL	ı					
ditic	AIS	М	ı	Add I to M, then skip if carry	$M \leftarrow (M) + I$, skip if carry	0	1	0	1	0	1	DH	DL	I					
Ad	AIC	М	ı	Add I to M with carry	$M \leftarrow (M) + I + C$	0	1	0	1	1	0	DH	DL	I					
	AICS	М	ı	Add I to M with carry, then skip if carry	$M \leftarrow (M) + I + C$, skip if carry	0	1	0	1	1	1	DH	DL	_					
	SU	r	М	Subtract M from r	$R \leftarrow (r) - (M)$	0	1	1	0	0	0	DH	DL	r					
ω l	SUS	r	М	Subtract M from r, then skip if borrow	$R \leftarrow (r) - (M),$ skip if borrow	0	1	1	0	0	1	DH	DL	r					
tion	SB	r	М	Subtract M from r with borrow	$R \leftarrow (r) - (M) - b$	0	1	1	0	1	0	DH	DL	r					
instruc	SBS	r	М	Subtract M from r with borrow, then skip if borrow	$R \leftarrow (r) - (M) - b$, skip if borrow	0	1	1	0	1	1	DH	DL	r					
tion	SI	М	ı	Subtract I from M	$M \leftarrow (M) - I$	0	1	1	1	0	0	DH	DL	I					
Subtraction instructions	SIS	М	ı	Subtract I from M, then skip if borrow	$M \leftarrow (M) - I$, skip if borrow	0	1	1	1	0	1	DH	DL	_					
0	SIB	М	1	Subtract I from M with borrow	$M \leftarrow (M) - I - b$	0	1	1	1	1	0	DH	DL						
	SIBS	М	ı	Subtract I from M with borrow, then skip if borrow	$M \leftarrow (M) - I - b$, skip if borrow	0	1	1	1	1	1	DH	DL	_					
S	SEQ	r	М	Skip if r equal to M	(r) – (M), skip if zero	0	0	0	1	0	0	DH	DL	r					
tion	SEQI	М	ı	Skip if M equal to I	(M) – I, skip if zero	0	0	0	1	1	0	DH	DL	I					
truc	SNEI	М		Skip if M not equal to I	(M) – I, skip if not zero	0	0	0	0	0	1	DH	DL	I					
son ins	SGE	r	М	Skip if r is greater than or equal to M	(r) – (M), skip if not borrow	0	0	0	1	1	0	DH	DL	r					
Comparison instructions	SGEI	М	ı	Skip if M is greater than equal to I	(M) – I, skip if not borrow	0	0	0	1	1	1	DH	DL	ı					
O	SLEI	М	ı	Skip if M is less than I	(M) – I, skip if borrow	0	0	0	0	1	1	DH	DL	I					

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tion Th	Magazzzia	Ope	rand	Function	Operation - formation	Instruction format	
Instruction group	Mnemonic	1st	2nd	Function	Operations function	f e d c b a 9 8 7 6 5 4 3 2 1	1 0
	AND	r	М	AND M with r	$R \leftarrow (r) \text{ AND } (M)$	0 0 1 0 0 0 DH DL r	
lctio	ANDI	М	ı	AND I with M	$M \leftarrow (M) \text{ AND I}$	0 0 1 0 0 1 DH DL I	
) stru	OR	r	М	OR M with r	0 0 1 0 1 0 DH DL r		
on ir	ORI	М	I	OR I with M	$M \leftarrow (M) \text{ OR } I$	0 0 1 0 1 1 DH DL I	
ratic	EXL	r	М	Exclusive OR M with r	$R \leftarrow (r) \text{ XOR (M)}$	0 0 1 1 0 0 DH DL r	
obe	EXLI	М	ı	Exclusive OR M with M	$M \leftarrow (M) \text{ XOR I}$	0 0 1 1 1 0 DH DL I	
Logic operation instructions	SHR	r		Shift r right with carry	carry (r)	0 0 0 0 0 0 0 0 1 1 1 0 r	
	LD	r	М	Load M to r	$R \leftarrow (M)$	1 1 0 1 0 0 DH DL r	
ons	ST	М	r	Store r to M	$M \leftarrow (r)$	1 1 0 1 0 1 DH DL r	
Transfer instructions	MVRD	r	М	Move M to destination M referring to r in the same row	$[DH, Rn] \leftarrow (M)$	1 1 0 1 1 0 DH DL r	
nsfer ir	MVRS	М	r	Move source M referring to r to M in the same row	M ← [DH, Rn]	1 1 0 1 1 1 DH DL r	
Tra	MVSR	M1	M2	Move M to M in the same row	[DH, DL1] ← [DH, DL2]	1 1 1 0 0 0 DH DL1 DL2	!
	MVI	М	ı	Move I to M	$M \leftarrow I$	1 1 1 0 0 1 DH DL I	
Bit test instructions	TMT	М	N	Test M bits, then skip if all bits specified are true	if M (N) = all 1, then skip	1 1 1 1 0 0 DH DL N	
Bit	TMF	М	N	Test M bits, then skip if all bits specified are false	if M (N) = all 0, then skip	1 1 1 1 0 1 DH DL N	
ne	JMP	AD	DR	Jump to the address	$PC \leftarrow ADDR$	1 0 0 ADDR (13 bits)	
ubrouti	CAL	AD	DR	Call subroutine	PC ← ADDR Stack ← (PC) + 1	1 0 1 ADDR (13 bits)	
ר שׁב ש Stru	RT	į		Return from subroutine	PC ← Stack	0 0 0 0 0 0 0 0 1 0 0 0	
Jump and subroutine call instructions	RTI			Return from interrupt	PC ← Stack, BANK ← Stack, CARRY ← Stack	0 0 0 0 0 0 0 1 0 0 1	
	SS	SWR	N	Set status register	(Status W-reg) N ← 1	1 1 1 1 1 1 1 1 0 0 0 SWR N	
ster	RS	SWR	N	Reset status register	(Status W-reg) N ← 0	1 1 1 1 1 1 1 0 0 1 SWR N	
regi	TST	SRR	N	Test status register true	If (Status R-reg) N = all	1 1 1 1 1 1 1 0 1 SRR N	
Status register instructions	TSF	SRR	N	Test status register false	If (Status R-reg) N = all	1 1 1 1 1 1 1 1 1 0 SRR N	
ŞŞ.	TUL	N		Test Unlock F/F	If Unlock F/F (N) = All 0s, then skip	0 0 0 0 0 0 0 0 1 1 0 1 N	
ons	PLL	N	Л	Load M to PLL register	PLL reg ← PLL data	1 1 1 1 1 0 DH DL r	
uctik	SIO	l1	12	Serial I/O control	SIO reg ← I1, I2	0 0 0 0 0 0 0 1 11 12	
ol instructions	UCS		I	Set I to UCCW1	UCCW1 ← I	0 0 0 0 0 0 0 0 0 0 0 1 I	
	UCC	İ	l	Set I to UCCW2	UCCW2 ← I	0 0 0 0 0 0 0 0 0 1 0 I	
Hardware cont	BEEP	1	I	Beep control	BEEP reg ← I	0 0 0 0 0 0 0 0 1 1 0 1	
/are	DZC		l	Dead zone control	DZC reg ← I	0 0 0 0 0 0 0 0 1 0 1 1	
ardw	TMS		l	Set timer register	Timer reg ← I	0 0 0 0 0 0 0 0 1 1 0 0	
ヹ	IOS	PWn	N	Set port control word	IOS reg PWn ← N	1 1 1 1 1 1 0 PWn N	
	IN	М	Pn	Input register port data to M	M ← (Pn)	1 1 1 0 1 0 DH DL Pn	
	OUT	М	Pn	Output contents of M to port	Pn ← M	1 1 1 0 1 1 DH DL Pn	
	INR	М	Rn	Input port data to M	M ← (Pn reg)	0 0 1 1 1 0 DH DL Pn	
I/O instructions	OUTR	М	Rn	Output contents of M to register/port	Rn reg ← (M)	0 0 1 1 1 1 DH DL Rn	
nstrı	SPB	Pn	N	Set port bits	(Pn)N ← 1	0 0 0 0 0 0 1 0 Pn N	
o	RPB	Pn	N	Reset port bits	(Pn)N ← 0	0 0 0 0 0 0 1 1 Pn N	
-	TPT	Pn	N	Test port1 bits, then skip if all bits specified are true	If (Pn)N = all 1, then skip	1 1 1 1 1 0 0 Pn N	
	TPF	Pn	N	Test port1 bits, then skip if all bits specified are false	If (Pn)N = all 0, then skip	1 1 1 1 1 0 1 Pn N	
Bank switching instructions	BANK		I	Select Bank	BANK ← I	0 0 0 0 0 0 0 0 0 1 1 1 1	

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rction oup	Instruction droup Mnemonic —	Ope	rand	Function	Operations function						Instruction format									
Instru		1st	2nd	i dilettori	Operations function	f	е	d	С	b	а	9	8	7	6	5	4	3	2	1 0
SI	LCDA	М	1	Output segment pattern to LCD	LCD (DIGIT) ← M	1	1	0	0	0	0	D	Н		D	L		DIGIT		
ctio	LCDB	М	1	digit direct	LCD (DIGIT) ← W	1	1	0	0	0	1	D	Н		D	L			DIG	ΤIέ
LCD instructions	LCPA	М	1	Output segment pattern to LCD	LCD (DIGIT) ← LA ← M	1	1	0	0	1	0 DH DL [DIG	ΤIέ					
. <u>≅</u>	LCPB	М	1	digit through LA		1	1	0	0	1	1	D	Н	DL				DIGIT		
Other instructions	HALT		I	Halt mode control	HALT reg ← I, then CPU clock stop	0	0	0	0	0	0	0	0	0	1	0	0	 	I	
Oth	CKSTP			Clock stop	Stop x'tal OSC	0	0	0	0	0	0	0	0	0	1	0	1			
ins	NOP			No operation	No operation	0	0	0	0	0	0	0	0	0	0	0	0			

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